

SILICON POWER TRANSISTOR 2SA1847

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1847 is a power transistor developed for high-speed switching and features a high here at low VCE(sat). This transistor is ideal for use as a driver in DC/DC converters and actuators.

In addition, this transistor features a package that can be auto-mounted in radial taping specifications, thus contributing to mounting cost reduction.

FEATURES

- · Auto-mount possible in radial taping specifications
- Resin-molded insulation type package with power rating of 1.8 W in stand-alone conditions
- High hee and low Vce(sat):

 $V_{CE(sat)} = -0.3 \text{ V MAX}. \ @ \text{Ic} = -6.0 \text{ V}, \ \text{Ib} = -0.3 \text{ A}$ $\text{hre} \ge 100 \ @ \text{Vce} = -2.0 \text{ V}, \ \text{Ic} = -2.0 \text{ A}$

· Fast switching speed

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		-150	٧
Collector to emitter voltage	VCEO		-100	٧
Emitter to base voltage	VEBO		-7.0	٧
Collector current (DC)	Ic(DC)		-10	Α
Collector current (pulse)	IC(pulse)	PW ≤ 300 <i>μ</i> s, duty cycle ≤ 2%	-20	Α
Base current (DC)	I _{B(DC)}		-6.0	Α
Total power dissipation	Рт	Ta = 25°C	1.8	W
Junction temperature	Tj		150	°C
Storage temperature	Tstg		−55 to +150	°C

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



ELECTRICAL4 CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = -100 V, IE = 0			-10	μΑ
Collector cutoff current	ICER	$V_{CE} = -100 \text{ V}, \text{ R}_{EB} = 50 \Omega$ $Ta = 125^{\circ}\text{C}$			-1.0	mA
Collector cutoff current	ICEX1	Vce = -100 V, VBE(off) = 1.5 V			-10	μΑ
Collector cutoff current	ICEX2	Vce = -100 V, Vbe(off) = 1.5 V Ta = 125°C			-1.0	mA
Emitter cutoff current	ІЕВО	V _{EB} = -5.0 V, I _C = 0			-10	μΑ
DC current gain	h _{FE1} *	Vce = -2.0 V, Ic = -0.5 A	100			-
DC current gain	hFE2*	Vce = -2.0 V, Ic = -2.0 A	100		400	-
DC current gain	h _{FE3} *	Vce = -2.0 V, Ic = -6.0 A	60			-
Collector saturation voltage	V _{CE(sat)1} *	Ic = -6.0 A, IB = -0.3 A			-0.3	V
Collector saturation voltage	V _{CE(sat)2} *	Ic = -8.0 A, IB = -0.4 A			-0.5	٧
Base saturation voltage	V _{BE(sat)1} *	Ic = -6.0 A, IB = -0.3 A			-1.2	٧
Base saturation voltage	V _{BE(sat)2} *	Ic = -8.0 A, IB = -0.4 A			-1.5	٧
Gain bandwidth product	f⊤	Vce = -10 V, Ic = -0.5 A		150		MHz
Collector capacitance	Cob	VcB = −10 V, IE = 0, f = 1 MHz		250		pF
Turn-on time	ton	Ic = -6.0 A			0.3	μs
Storage time	tstg	$I_{B1} = -I_{B2} = -0.3 \text{ A}$ $R_L = 8.3 \Omega, \text{ Voc} = -50 \text{ V}$			1.5	μs
Fall time	tf	11L - 0.0 22, VCC30 V			0.4	μs

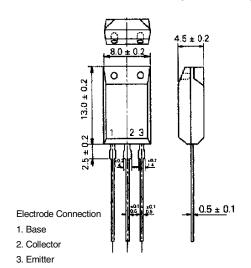
^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

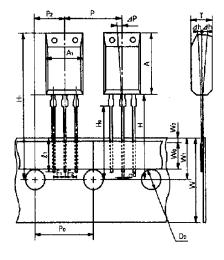
hfe CLASSIFICATION

Marking	М	L	K	
hfe	100 to 200	150 to 300	200 to 400	

PACKAGE DRAWING (UNIT: mm)

TAPING SPECIFICATION

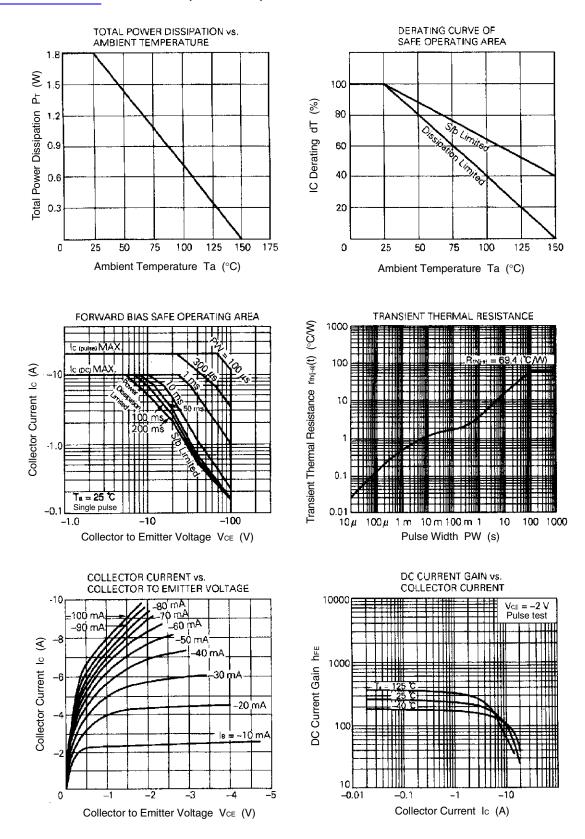




Αı	8.0 ± 0.2
Α	13.0 ± 0.2
Dο	ϕ 4.0 ± 0.2
d	0.5 ± 0.1
F۱	2.5+0.4
F ₂	2.5-0.4
н	20.0 MAX.
Ho	16.0 ± 0.5
Hı	32.2 MAX.
⊿fh	0 ± 1.0
٤ı	2.5 MIN.
Р	12.7 ± 1.0
P₀	12.7 ± 0.3
P₂	6.35 ± 0.5
ΔP	0 ± 1.3
T	4.5 ± 0.2
W	18.0+1.0
₩o	5.0 MIN.
Wi	9.0 ± 0.5
VV2	0.7 MIN.
	·



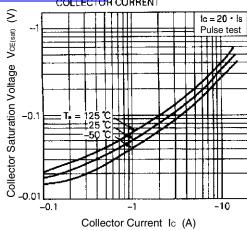
查询"12814102417"(共区FIA)CTERISTICS (Ta = 25°C)



Data Sheet D15593EJ2V0DS

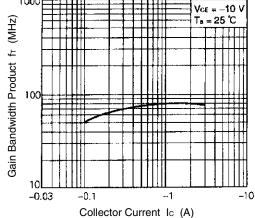
3

查询"2SA1847"战底商R SATURATION VOLTAGE vs.

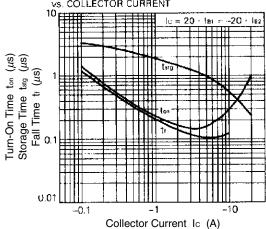


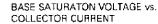


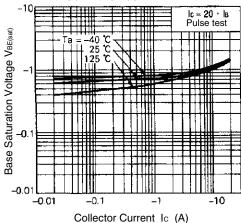
GAIN BANDWIDTH PRODUCT vs.



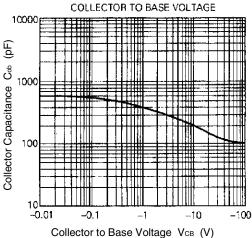






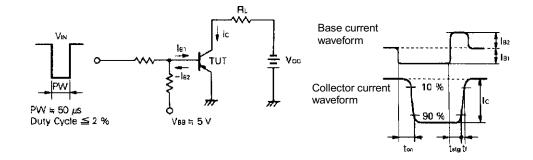


OUTPUT CAPACITANCE vs.





查询SWATCATN供应酶 (ton, tstg, tf) TEST CIRCUIT





查询"2SA1847"供应商

- The information in this document is current as of July, 2001. The information is subject to change
 without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data
 books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products
 and/or types are available in every country. Please check with an NEC sales representative for
 availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of
 third parties by or arising from the use of NEC semiconductor products listed in this document or any other
 liability arising from the use of such products. No license, express, implied or otherwise, is granted under any
 patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
 purposes in semiconductor product operation and application examples. The incorporation of these
 circuits, software and information in the design of customer's equipment shall be done under the full
 responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third
 parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
 agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
 risks of damage to property or injury (including death) to persons arising from defects in NEC
 semiconductor products, customers must incorporate sufficient safety measures in their design, such as
 redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
 - "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.
 - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

- (Note)
- (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).